

RJH1CV5DPQ-E0

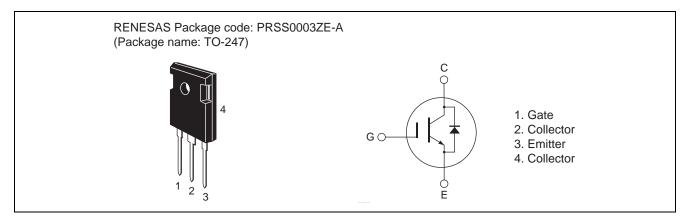
1200V - 25A - IGBT Application: Inverter

R07DS0523EJ0400 Rev.4.00 Jan 19, 2012

Features

- Short circuit withstand time (5 µs typ.)
- Low collector to emitter saturation voltage $V_{CE(sat)}=1.8~V$ typ. (at $I_C=25~A,~V_{GE}=15~V,~Ta=25^{\circ}C$)
- Built-in fast recovery diode ($t_{rr} = 200 \text{ ns typ.}$) in one package
- Trench gate and thin wafer technology
- High speed switching t_f = 200 ns typ. (at V_{CC} = 600 V, V_{GE} = 15 V, I_C = 25 A, Rg = 5 Ω , Ta = 25°C, inductive load)

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V _{CES} / V _R	1200	V
Gate to emitter voltage		V_{GES}	±30	V
Collector current	Tc = 25°C	I _C	50	А
	Tc = 100°C	I _C	25	А
Collector peak current		ic(peak) Note1	75	А
Collector to emitter diode forward current		I _{DF}	25	А
Collector to emitter diode forward peak current		i _{DF} (peak) Note1	75	А
Collector dissipation		P _C Note2	260.4	W
Junction to case thermal resistance (IGBT)		θj-c Note2	0.48	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at Tc = 25°C

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Electrical Characteristics

 $(Ta = 25^{\circ}C)$

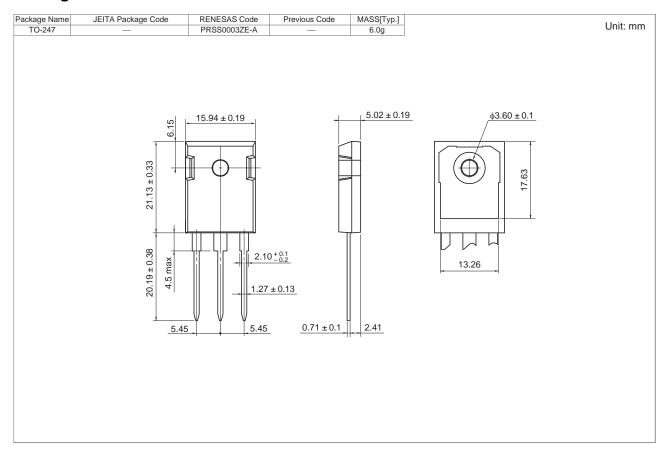
Item	Symbol	Min	Тур	Max	Unit	Test Conditions
Zero gate voltage collector current	I _{CES} /I _R	_	_	5	μΑ	$V_{CE} = 1200 \text{ V}, V_{GE} = 0$
/ Diode reverse current						
Gate to emitter leak current	I _{GES}	—	—	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$
Gate to emitter cutoff voltage	$V_{GE(off)}$	4	_	8	V	$V_{CE} = 10 \text{ V}, I_{C} = 1 \text{ mA}$
Collector to emitter saturation voltage	V _{CE(sat)}	_	1.8	_	V	$I_C = 25 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$
Input capacitance	Cies	_	1100	_	pF	V _{CE} = 25 V
Output capacitance	Coes	_	40	_	pF	$V_{GE} = 0$
Reveres transfer capacitance	Cres	_	25	_	pF	f = 1 MHz
Switching time	t _{d(on)}	_	40	_	ns	$V_{CC} = 600 \text{ V}, V_{GE} = 15 \text{ V}$ $I_C = 25 \text{ A}$ $Rg = 5 \Omega$ Inductive load
	t _r	_	15	_	ns	
	t _{d(off)}	_	90	_	ns	
	t _f	_	200	_	ns	
Short circuit withstand time	t _{sc}	_	5	_	μS	$V_{CC} \le 720 \text{ V}, V_{GE} = 15 \text{ V}$
						Tc ≤ 125°C

FRD forward voltage	V_{F}	_	1.7	_	V	$I_F = 25 \text{ A}^{\text{Note3}}$
FRD reverse recovery time	t _{rr}	_	200	_	ns	I _F = 25 A
						di _F /dt = 100 A/μs

Notes: 3. Pulse test.

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Package Dimension



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJH1CV5DPQ-E0#T2	450 pcs	Box (Tube)

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